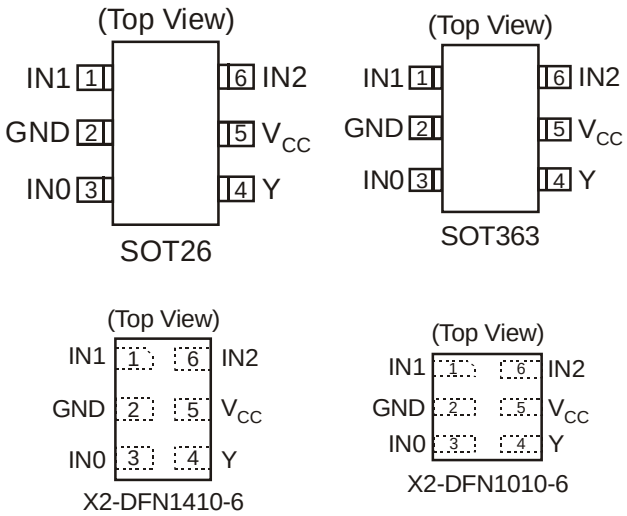
74LVC1G98

CONFIGURABLE MULTIPLE-FUNCTION GATE

Description

The 74LVC1G98 is a single 3-input positive configurable multiple function gate with a standard push-pull output. The output state is determined by eight patterns of 3-bit input. The user can chose the logic functions MUX, AND, OR, NAND, NOR, inverter or non-inverting buffer. All inputs can be connected to ground or V_{CC} as required. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down. The user is reminded that the device can simulate several types of logic gates but may respond differently due to the Schmitt action at the inputs.

Pin Assignments



Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- SOT26, SOT363, DFN1410, and DFN1010: Available in "Green" Molding Compound (no Br, Sb)
  - **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
  - **Halogen and Antimony Free. "Green" Device (Note 3)**

Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - Cell Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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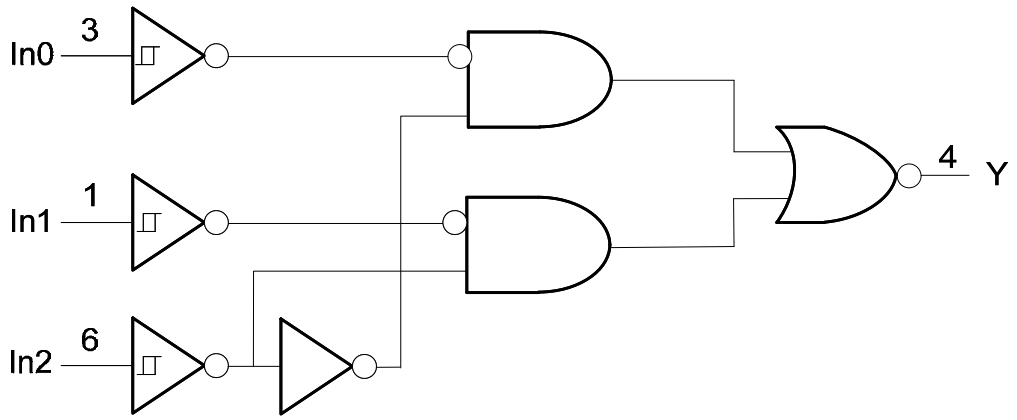
Pin Descriptions

Pin Name	Function
IN1	Data Input
GND	Ground
IN0	Data Input
Y	Data Output
V_{CC}	Supply Voltage
IN2	Data Input

Logic Diagram



Function Table

Inputs			Output
IN2	IN1	IN0	Y
L	L	L	H
L	L	H	H
L	H	L	L
L	H	H	L
H	L	L	H
H	L	H	L
H	H	L	H
H	H	H	L

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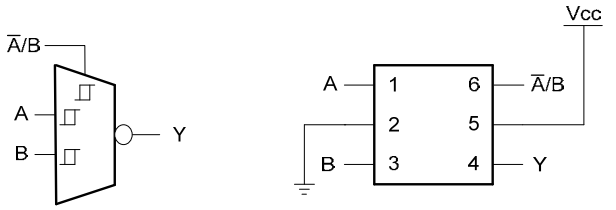
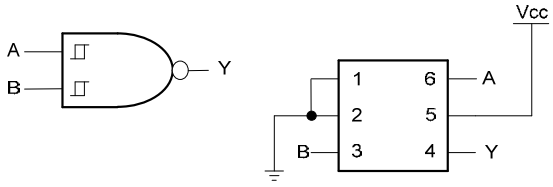
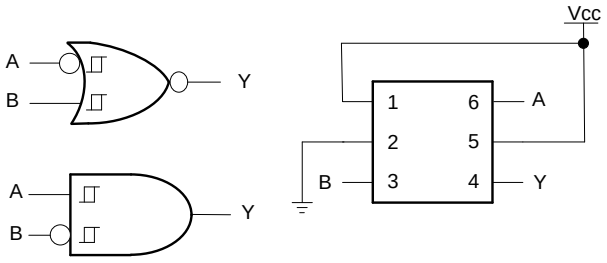
Logic Configurations



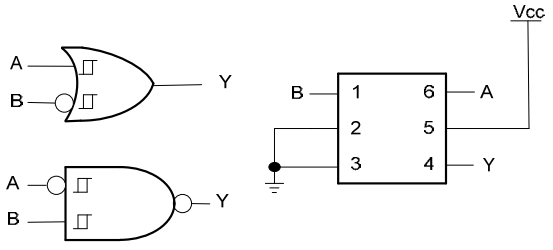
Configuration 1
2 to 1 Data Selector with Inverted Output



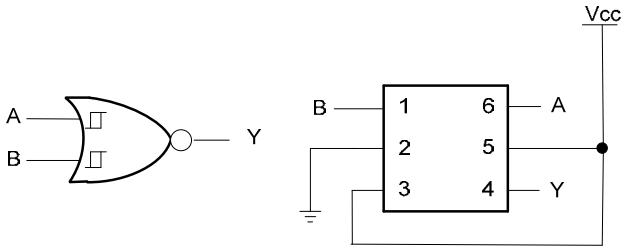
Configuration 2
2-Input NAND Gate
2-Input OR Gate with Both Inputs Inverted



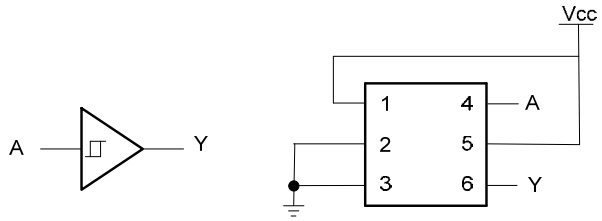
Configuration 3
2-Input NAND Gate with B Input Inverted
2-Input OR Gate with A Input Inverted



Configuration 4
2-Input OR Gate with One Input Inverted
2-Input NAND Gate with One Input Inverted



Configuration 5
2-Input NOR Gate



Configuration 6
Buffer

Function Selection Table	
Logic Function	**Configuration**
2-to-1 Data Selector with inverted output	1
2-input NAND gate	2
2-input AND with inverted input	3
2-input NOR with inverted input	3
2-input NAND with one inverted input	4
2-input OR with one inverted input	4
2-input NOR	5
1-input Buffer	6

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Absolute Maximum Ratings (Note 4)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +6.5	V
V_I	Input Voltage Range	-0.5 to +6.5	V
V_O	Voltage applied to output in high impedance or I_{OFF} state	-0.5 to +6.5	V
V_O	Voltage applied to output in high or low state	-0.3 to V_{CC} +0.5	V
I_{IK}	Input Clamp Current V_I<0	-50	mA
I_{OK}	Output Clamp Current	-50	mA
I_O	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
T_J	Operating Junction Temperature	-40 to +150	°C
T_{STG}	Storage Temperature	-65 to +150	°C

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage	Operating	1.65	5.5	V
		Data retention only	1.5		V
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 1.65V		-4	mA
		V_{CC} = 2.3V		-8	
		V_{CC} = 3V		-16	
				-24	
		V_{CC} = 4.5V		-32	
I_{OL}	Low-level output current	V_{CC} = 1.65V		4	mA
		V_{CC} = 2.3V		8	
		V_{CC} = 3V		16	
				24	
		V_{CC} = 4.5V		32	
Δt/ΔV	Input transition rise or fall rate	V_{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V		20	ns/V
		V_{CC} = 3.3V ± 0.3V		10	
		V_{CC} = 5 V ± 0.5V		5	
T_A	Operating free-air temperature		-40	+125	°C

Notes: 5. Unused inputs should be held at V_{CC} or Ground.

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Electrical Characteristics T_A = -40°C to +85°C (All typical values are at V_{CC} = 3.3V, T_A = +25°C)

Symbol	Parameter	Test Conditions	V_{CC}	Min	Typ.	Max	Unit
V_{T+}	Positive-going input threshold voltage		1.65V	0.70		1.20	
			2.3V	1.11		1.60	
			3V	1.50		2.00	
			4.5V	2.16		2.74	
			5.5V	2.61		3.33	
V_{T-}	Negative-going input threshold voltage		1.65V	0.30		0.72	
			2.3V	0.58		1.00	
			3V	0.80		1.30	
			4.5V	1.21		1.95	
			5.5V	1.45		2.35	
ΔV_T	Hysteresis (V_{T+} - V_{T-})		1.65V	0.30		0.62	
			2.3V	0.40		0.80	
			3V	0.35		1.00	
			4.5V	0.55		1.10	
			5.5V	0.60		1.20	
V_{OH}	High Level Output Voltage	I_{OH} = -100µA	1.65V to 5.5V	V_{CC} – 0.1			V
		I_{OH} = -4mA	1.65V	1.2			
		I_{OH} = -8mA	2.3V	1.9			
		I_{OH} = -16mA	3V	2.4			
		I_{OH} = -24mA		2.3			
		I_{OH} = -32mA	4.5V	3.8			
V_{OL}	High-level Input Voltage	I_{OL} = 100µA	1.65V to 5.5V			0.1	V
		I_{OL} = 4mA	1.65V			0.45	
		I_{OL} = 8mA	2.3V			0.3	
		I_{OL} = 16mA	3V			0.4	
		I_{OL} = 24mA				0.55	
		I_{OL} = 32mA	4.5V			0.55	
I_I	Input Current	V_I = 5.5V or GND	0 to 5.5V			± 5	µA
I_{OFF}	Power Down Leakage Current	V_I or V_O = 5.5V	0			± 10	µA
I_{CC}	Supply Current	V_I = 5.5V of GND I_O = 0	1.65V to 5.5V			10	µA
ΔI_{CC}	Additional Supply Current	One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	3V to 5.5V			500	µA

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Electrical Characteristics T_A = -40°C to +125°C (All typical values are at V_{CC} = 3.3V, T_A = +25°C)

Symbol	Parameter	Test Conditions	V_{CC}	Min	Typ	Max	Unit
V_{T+}	Positive-going input threshold voltage		1.65V	0.70		1.20	
			2.3V	1.11		1.60	
			3V	1.50		2.00	
			4.5V	2.16		2.74	
			5.5V	2.61		3.33	
V_{T-}	Negative-going input threshold voltage		1.65V	0.30		0.75	
			2.3V	0.58		1.03	
			3V	0.80		1.33	
			4.5V	1.21		1.95	
			5.5V	1.45		2.35	
ΔV_T	Hysteresis (V_{T+} - V_{T-})		1.65V	0.30		0.62	
			2.3V	0.37		0.80	
			3V	0.32		1.00	
			4.5V	0.50		1.20	
			5.5V	0.55		1.40	
V_{OH}	High Level Output Voltage	I_{OH} = -100µA	1.65V to 5.5V	V_{CC} – 0.1			V
		I_{OH} = -4mA	1.65V	0.95			
		I_{OH} = -8mA	2.3V	1.7			
		I_{OH} = -16mA	3V	1.9			
		I_{OH} = -24mA		2.0			
		I_{OH} = -32mA	4.5V	3.4			
V_{OL}	High-level Input Voltage	I_{OL} = 100µA	1.65V to 5.5V			0.1	V
		I_{OL} = 4mA	1.65V			0.7	
		I_{OL} = 8mA	2.3V			0.45	
		I_{OL} = 16mA	3V			0.6	
		I_{OL} = 24mA				0.8	
		I_{OL} = 32mA	4.5V			0.8	
I_I	Input Current	V_I = 5.5V or GND	0 to 5.5V			± 100	µA
I_{OFF}	Power Down Leakage Current	V_I or V_O = 5.5V	0			± 200	µA
I_{CC}	Supply Current	V_I = 5.5V of GND I_O=0	1.65V to 5.5V			200	µA
ΔI_{CC}	Additional Supply Current	One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	3V to 5.5V			5000	µA

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Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C)

Symbol	Parameter	Test Conditions	V_{CC}	Min	Typ	Max	Unit
C_I	Input Capacitance	V_I = V_{CC} – or GND	3.3		3.5		pF
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT26	(Note 6)		204		°C/W
		SOT363			371		
		X2-DFN1410-6			430		
		X2-DFN1010-6			510		
θ_{JC}	Thermal Resistance Junction-to-Case	SOT26	(Note 6)		52		°C/W
		SOT363			143		
		X2-DFN1410-6			190		
		X2-DFN1010-6			250		

Notes: 6. Test condition for SOT26, SOT363, X2-DFN1410-6 and X2-DFN1010-6: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

T_A = -40°C to +85°C, C_L = 30 or 50pF as noted (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)	V_{CC} = 1.8V ± 0.15V		V_{CC} = 2.5V ± 0.2V		V_{CC} = 3.3V ± 0.3V		V_{CC} = 5V ± 0.5V		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	Any	Y	1.0	14.4	0.7	8.3	0.7	6.3	0.7	5.1	ns

T_A = -40°C to +125°C, C_L = 30 or 50pF as noted (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)	V_{CC} = 1.8V ± 0.15V		V_{CC} = 2.5V ± 0.2V		V_{CC} = 3.3V ± 0.3V		V_{CC} = 5V ± 0.5V		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	Any	Y	1.0	18.0	0.7	10.4	0.7	7.9	0.7	6.4	ns

Operating Characteristics

T_A = +25°C

Parameter		Test Conditions	V_{CC} = 1.8V	V_{CC} = 2.5V	V_{CC} = 3.3V	V_{CC} = 5V	Unit
			Typ	Typ	Typ	Typ	
C_{pd}	Power dissipation capacitance	f = 10 MHz	22	22	23	24	pF

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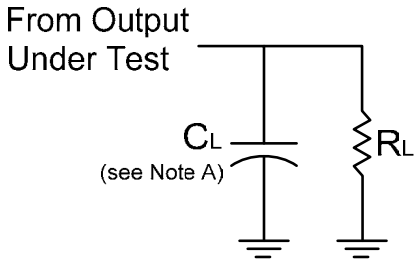
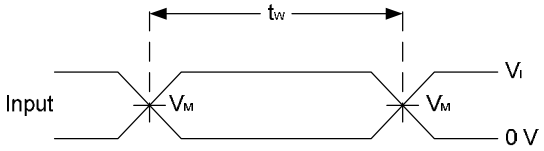
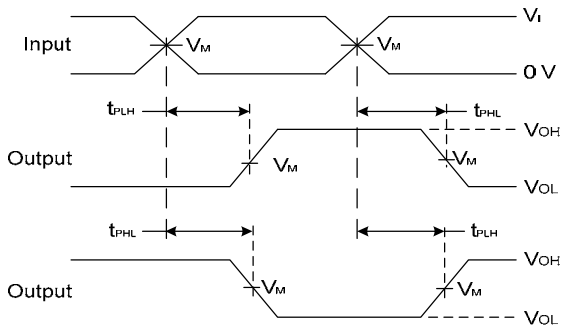
Parameter Measurement Information



V_{CC}	Inputs		V_M	C_L	R_L
	V_I	t_r/t_f			
1.8V±0.15V	V_{CC}	≤2ns	$V_{CC}/2$	30pF	1KΩ
2.5V±0.2V	V_{CC}	≤2ns	$V_{CC}/2$	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V_{CC}	≤2.5ns	$V_{CC}/2$	50pF	500Ω



Voltage Waveform
Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
C. Inputs are measured separately one transition per measurement
D. t_{PLH} and t_{PHL} are the same as t_{PD}

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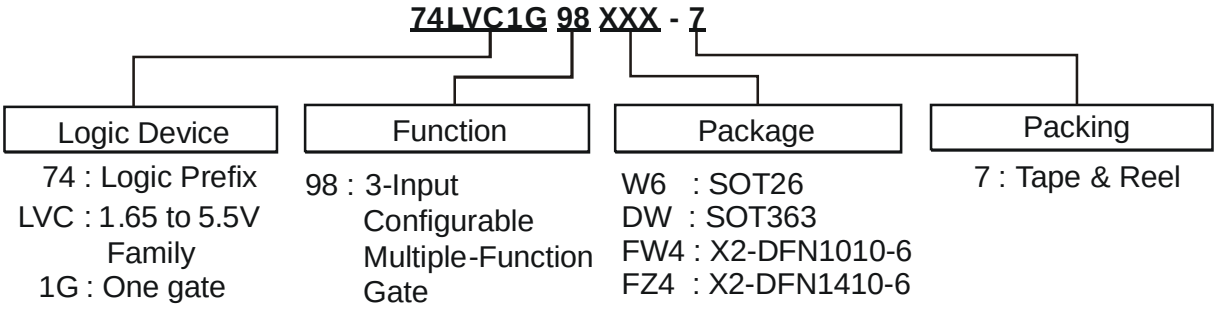
Ordering Information



Device	Package Code	Packaging (Note 7)	7" Tape and Reel	
			Quantity	Part Number Suffix
74LVC1G98W6-7	W6	SOT26	3000/Tape & Reel	-7
74LVC1G98DW-7	DW	SOT363	3000/Tape & Reel	-7
74LVC1G98FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74LVC1G98FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7

Notes: 7. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

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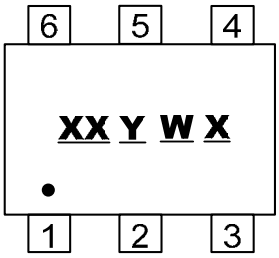
Marking Information

(1) SOT26, SOT363

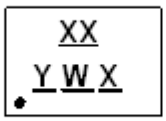


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents 52 and 53 week
X : A~Z : Internal Code

Part Number	Package	Identification Code
74LVC1G98W6	SOT26	TZ
74LVC1G98DW	SOT363	TZ

(2) X2-DFN1010-6, X2-DFN1410-6

(Top View)



XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents 52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74LVC1G98FW4	X2-DFN1010-6	TZ
74LVC1G98Z4	X2-DFN1410-6	TZ

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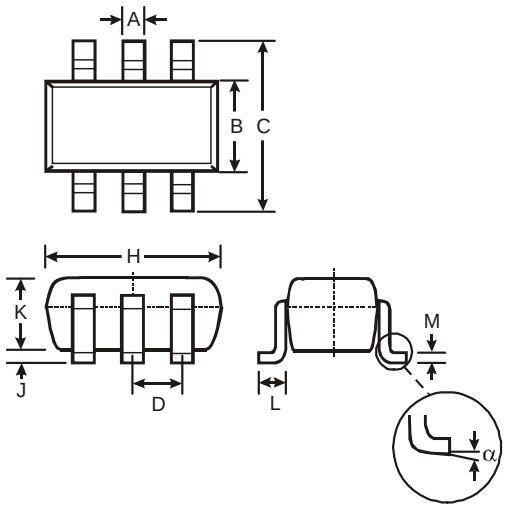
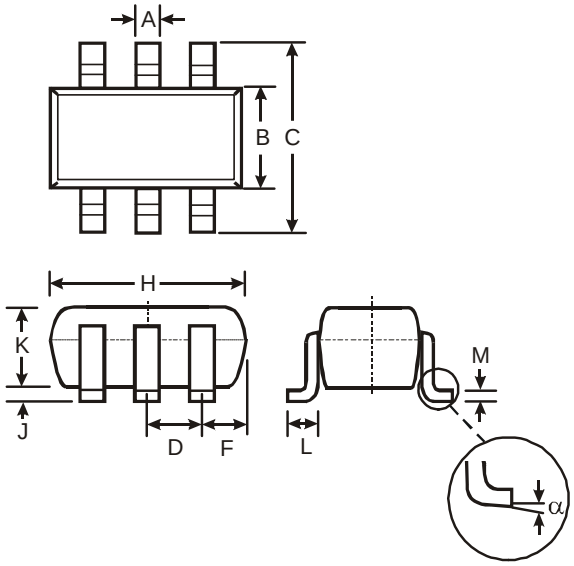
Package Outline Dimensions (All Dimensions in mm)

(1) SOT26



SOT26			
Dim	**Min**	**Max**	**Typ**
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

(2) SOT363



SOT363		
Dim	**Min**	**Max**
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

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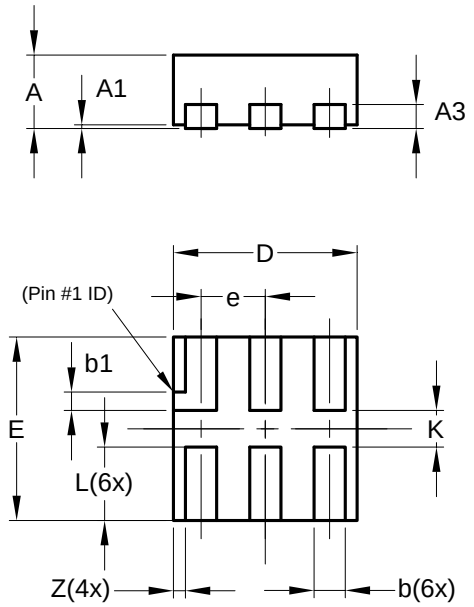
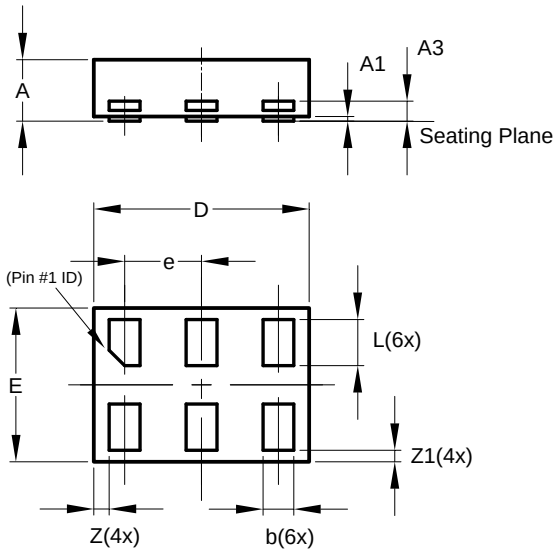
Package Outline Dimensions (All Dimensions in mm)

(3) X2-DFN1010-6



X2-DFN1010-6			
Dim	**Min**	**Max**	**Typ**
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
E	0.95	1.05	1.00
e	—	—	0.35
L	0.35	0.45	0.40
K	0.15	—	—
Z	—	—	0.065
All Dimensions in mm			

(4) X2-DFN1410-6



X2-DFN1410-6			
Dim	**Min**	**Max**	**Typ**
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
e	—	—	0.50
L	0.25	0.35	0.30
Z	—	—	0.10
Z1	0.045	0.105	0.075
All Dimensions in mm			

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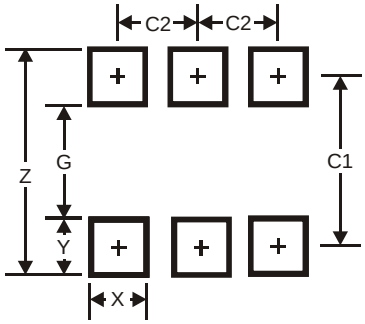
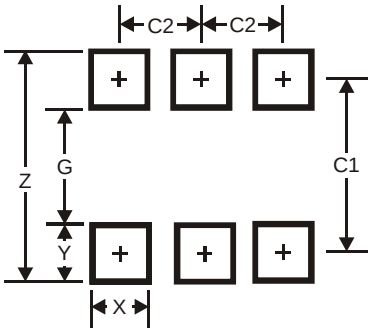
Suggest Pad Layout

(1) SOT26



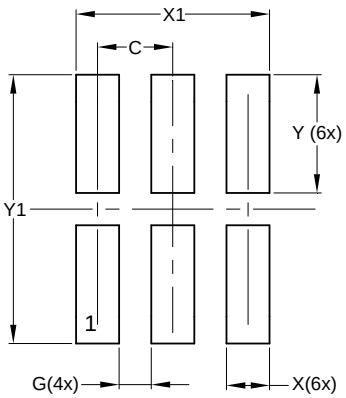
Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

(2) SOT363



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

(3) X2-DFN1010-6



Dimensions	Value (in mm)
C	0.350
G	0.150
X	0.200
X1	0.900
Y	0.550
Y1	1.250

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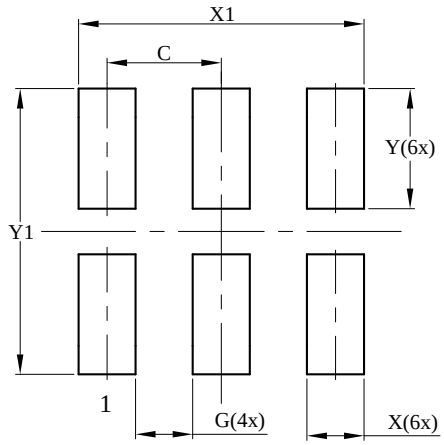
Suggest Pad Layout

(4) X2-DFN1410-6



Dimensions	Value (in mm)
C	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250

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